500 Watt Peak Power MiniMOSORB[™] Zener Transient Voltage Suppressors

Unidirectional

The SA5.0A series is designed to protect voltage sensitive components from high voltage, high energy transients. They have excellent clamping capability, high surge capability, low zener impedance and fast response time. The SA5.0A series is supplied in ON Semiconductor's exclusive, cost-effective, highly reliable Surmetic[™] axial leaded package and is ideally-suited for use in communication systems, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications.

Features

- Working Peak Reverse Voltage Range 5.0 to 170 V
- Peak Power 500 Watts @ 1.0 ms
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- Maximum Clamp Voltage @ Peak Pulse Current
- Low Leakage $< 1 \ \mu A$ above 8.5 V
- UL 497B for Isolated Loop Circuit Protection
- Maximum Temperature Coefficient Specified
- Response Time is typically < 1.0 ns
- Pb–Free Packages are Available*

Mechanical Characteristics:

CASE: Void-free, Transfer-molded, Thermosetting Plastic **FINISH:** All external surfaces are corrosion resistant and leads are readily solderable

MAXIMUM LEAD TEMPERATURE FOR SOLDERING: 230°C,

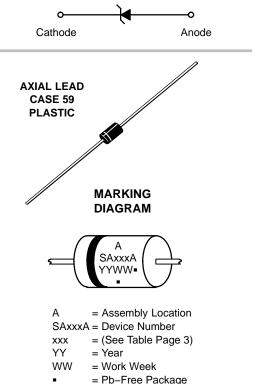
1/16 in. from the case for 10 seconds

POLARITY: Cathode indicated by polarity band **MOUNTING POSITION:** Any



ON Semiconductor®

http://onsemi.com



(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
SAxxxA	Axial Lead	1000 Units / Box
SAxxxAG	Axial Lead (Pb–Free)	1000 Units / Box
SAxxxARL*	Axial Lead	5000 / Tape & Reel
SAxxxARLG*	Axial Lead (Pb–Free)	5000 / Tape & Reel
SAxxxALF**	Axial Lead	2000 Units / Box
SAxxxALFG**	Axial Lead (Pb-Free)	2000 Units / Box

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*SA8.0A, SA130A, and SA160A Not Available in 5000 Reel.

** Lead formed device.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

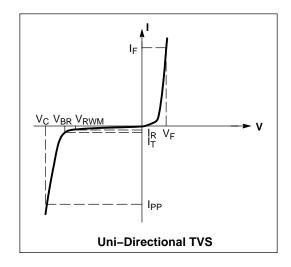
Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1) @ $T_L \leq 25^{\circ}C$	P _{PK}	500	W
Steady State Power Dissipation	P _D	3.0	W
@ $T_L \le 75^{\circ}$ C, Lead Length = 3/8 in Derated above $T_L = 75^{\circ}$ C		30	mW/°C
Thermal Resistance, Junction-to-Lead	R _{θJL}	33.3	°C/W
Forward Surge Current (Note 2) @ $T_A = 25^{\circ}C$	I _{FSM}	70	A
Operating and Storage Temperature Range	T _J , T _{stg}	– 55 to +175	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Nonrepetitive current pulse per Figure 4 and derated above $T_A = 25^{\circ}C$ per Figure 2. 2. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 3.5 V Max. @ I_F (Note 6) = 35 A)

Symbol	Parameter					
I _{PP}	Maximum Reverse Peak Pulse Current					
V _C	Clamping Voltage @ IPP					
V _{RWM}	Working Peak Reverse Voltage					
I _R	Maximum Reverse Leakage Current @ V_{RWM}					
V _{BR}	Breakdown Voltage @ I _T					
Ι _Τ	Test Current					
ΘV_{BR}	Maximum Temperature Variation of VBR					
١ _F	Forward Current					
V _F	Forward Voltage @ I _F					



ELECTRICAL CHARACTERISTICS (T _A = 25°C unless otherwise noted, V _F = 3.5 V Max. @ I _F (Note 6) = 3

	-	V _{RWM}	$(T_{A} = 25^{\circ}C \text{ unless otherwise noted}, V_{F} = 3.5 \text{ V Max. @ }I_{F} \text{ (Note 6)} = 35 \text{ A})$ Breakdown Voltage $V_{C} @ I_{PP} \text{ (Note 5)}$					(Note 5)		
	Device	(Note 3)	I _R @ V _{RWM}	V _{BR} (Note 4) (Volts)		@ I _T	V _C	I _{PP}	ΘV _{BR}	
Device*	Marking	Volts	μ Α	Min	Nom	Max	mA	Volts	Α	mV/°C
SA5.0A, G	SA5.0A	5	600	6.4	6.7	7	10	9.2	54.3	5
SA6.0A, G	SA6.0A	6	600	6.67	7.02	7.37	10	10.3	48.5	5
SA7.0A, G	SA7.0A	7	150	7.78	8.19	8.6	10	12	41.7	6
SA7.5A, G	SA7.5A	7.5	50	8.33	8.77	9.21	1	12.9	38.8	7
SA8.0A, G†	SA8.0A	8	25	8.89	9.36	9.83	1	13.6	36.7	7
SA8.5A, G	SA8.5A	8.5	5	9.44	9.92	10.4	1	14.4	34.7	8
SA9.0A, G	SA9.0A	9	1	10	10.55	11.1	1	15.4	32.5	9
SA10A, G	SA10A	10	1	11.1	11.7	12.3	1	17	29.4	10
SA11A, G	SA11A	11	1	12.2	12.85	13.5	1	18.2	27.4	11
SA12A, G	SA12A	12	1	13.3	14	14.7	1	19.9	25.1	12
SA13A, G	SA13A	13	1	14.4	15.15	15.9	1	21.5	23.2	13
SA14A, G	SA14A	14	1	15.6	16.4	17.2	1	23.2	21.5	14
SA15A, G	SA15A	15	1	16.7	17.6	18.5	1	24.4	20.6	16
SA16A, G	SA16A	16	1	17.8	18.75	19.7	1	26	19.2	17
SA17A, G	SA17A	17	1	18.9	19.9	20.9	1	27.6	18.1	19
SA18A, G	SA18A	18	1	20	21.05	22.1	1	29.2	17.2	20
SA20A, G	SA20A	20	1	22.2	23.35	24.5	1	32.4	15.4	23
SA22A, G	SA22A	22	1	24.4	25.65	26.9	1	35.5	14.1	25
SA24A, G	SA24A	24	1	26.7	28.1	29.5	1	38.9	12.8	28
SA26A, G	SA26A	26	1	28.9	30.4	31.9	1	42.1	11.9	30
SA28A, G	SA28A	28	1	31.1	32.75	34.4	1	45.4	11	31
SA30A, G	SA30A	30	1	33.3	35.05	36.8	1	48.4	10.3	36
SA33A, G	SA33A	33	1	36.7	38.65	40.6	1	53.3	9.4	39
SA36A, G	SA36A	36	1	40	42.1	44.2	1	58.1	8.6	41
SA40A, G	SA40A	40	1	44.4	46.55	49.1	1	64.5	7.8	46
SA43A, G	SA43A	43	1	47.8	50.3	52.8	1	69.4	7.2	50
SA45A, G	SA45A	45	1	50	52.65	55.3	1	72.7	6.9	52
SA48A, G	SA48A	48	1	53.3	56.1	58.9	1	77.4	6.5	56
SA51A, G	SA51A	51	1	56.7	59.7	62.7	1	82.4	6.1	61
SA58A, G	SA58A	58	1	64.4	67.8	71.2	1	93.6	5.3	70
SA60A, G	SA60A	60	1	66.7	70.2	73.7	1	96.8	5.2	71
SA64A, G	SA64A	64	1	71.1	74.85	78.6	1	103	4.9	76
SA64ALF, G	SA64A	64 70	1	71.1	74.85	78.6	1	103	4.9	76
SA70A, G	SA70A	70	1	77.8	81.9	86	1	113	4.4	85
SA78A, G	SA78A	78	1	86.7	91.25	95.8	1	126	4.0	95
SA90A, G	SA90A	90	1	100	105.5	111	1	146	3.4	110 122
SA100A, G	SA100A	100	1	111	117	123	1	162	3.1	123
SA110A, G	SA110A	110 120	1	122	128.5	135	1	177	2.8	133
SA120A, G	SA120A	120 130	1	133	140 151 5	147	1	193 200	2.5	146 158
SA130A, G† SA150A, G	SA130A SA150A	130 150	1	144 167	151.5 176	159 185	1 1	209 243	2.4 2.1	158 184
					176					
SA160A, G†	SA160A	160 170	1	178	187.5	197	1	259 275	1.9	196
SA170A, G	SA170A	170	1	189	199	209	1	275	1.8	208

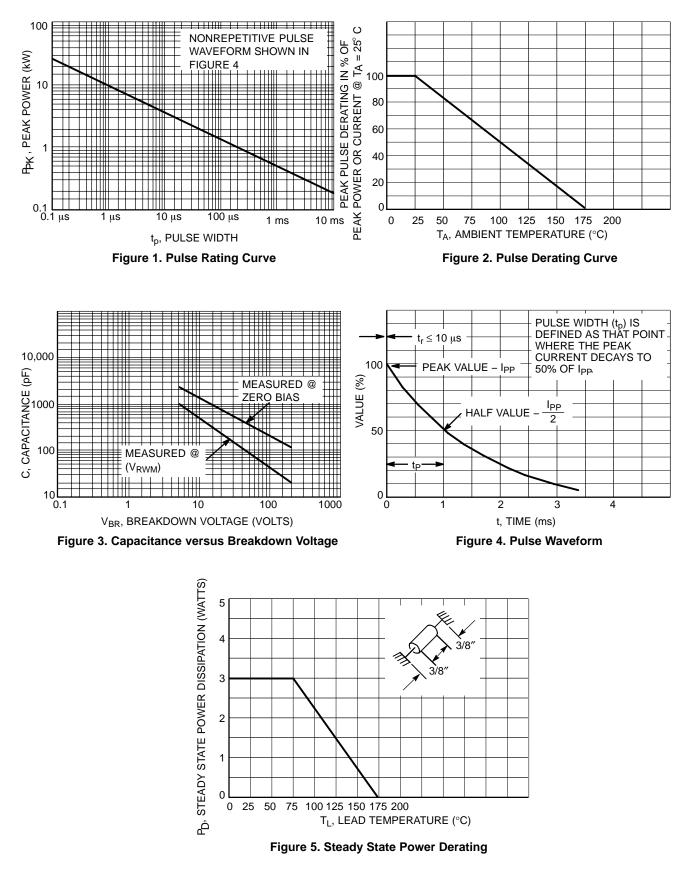
NOTE: Devices listed in bold, italic are ON Semiconductor Preferred devices. Preferred devices are recommended choices for future use and best overall value.

3. MiniMOSORB[™] transients suppressor is normally selected according to the maximum working peak reverse voltage (V_{RWM}), which should be equal to or greater than the dc or continuous peak operating voltage level.

4. V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C.

S. Surge current waveform per Figure 4 and derate per Figures 1 and 2.
 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute *The "G" suffix indicates Pb–Free package available.

†Not Available in the 5000/Tape & Reel.



UL RECOGNITION*

The entire series including the bidirectional CA suffix has *Underwriters Laboratory Recognition* for the classification of protectors (QVGV2) under the UL standard for safety 497B and File #E 116110. Many competitors only have one or two devices recognized or have recognition in a non-protective category. Some competitors have no recognition at all. With the UL497B recognition, our parts successfully passed several tests including Strike Voltage

Breakdown test, Endurance Conditioning, Temperature test, Dielectric Voltage-Withstand test, Discharge test and several more.

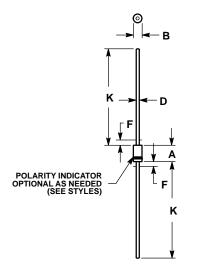
Whereas, some competitors have only passed a flammability test for the package material, we have been recognized for much more to be included in their protector category.

*Applies to SA5.0A, CA - SA170A, CA.

PACKAGE DIMENSIONS

MiniMOSORB

CASE 59-10 ISSUE U



NOTES: NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. ALL RULES AND NOTES ASSOCIATED WITH JEDEC DO-41 OUTLINE SHALL APPLY 4. POLARITY DENOTED BY CATHODE BAND. 5. LEAD DIAMETER NOT CONTROLLED WITHIN F DIMENSION

- DIMENSION

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.161	0.205	4.10	5.20		
В	0.079	0.106	2.00	2.70		
D	0.028	0.034	0.71	0.86		
F		0.050		1.27		
ĸ	1.000		25.40			

STYLE 1:

PIN 1. CATHODE (POLARITY BAND) 2. ANODE

MiniMOSORB and Surmetic are trademarks of Semiconductor Components Industries, LLC.

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.